

FRED

Ultrafast Soft Recovery Diode, 650V, 5A×2

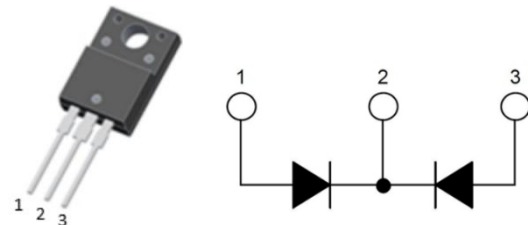
Description:

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery character of the diodes offers buffer in most applications. These devices are suited for power converters and other applications where the switching losses are not significant portion of the total losses.

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low IR value
- High surge capacity
- Epitaxial chip construction

Product Summary	
V_R	650 V
$I_{F(AV)}$	2×5 A
t_{rr}	35 ns



Applications:

- Switched mode power supply
- Freewheeling diode, snubber diode
- Uninterruptible power supplies (UPS)

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	V_{RRM}		650	V
Continuous forward current	$I_{F(AV)}$	$T_A=110^\circ\text{C}$	10	A
Single pulse forward current	I_{FSM}	$T_A=25^\circ\text{C}$	80	A
Maximum repetitive forward current	I_{FRM}	Square wave, 20kHz	25	A
Operating junction	T_j		175	$^\circ\text{C}$
Storage temperatures	T_{stg}		-55 to +175	$^\circ\text{C}$

Electrical characteristics ($T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Breakdown voltage	V_{BR}	$I_R=100\mu\text{A}$	650			V
Blocking voltage	V_R					
Forward voltage	V_F	$I_F=5\text{ A}$		1.30	1.60	V
		$I_F=5\text{ A}, T_j=125^\circ\text{C}$		1.20	1.50	V
Reverse leakage current	I_R	$V_R=V_{RRM}$			20	μA
		$T_j=150^\circ\text{C}, V_R=650\text{V}$			200	μA
Reverse recovery time	t_{rr}	$I_F=0.5\text{A}, I_R=1\text{A}, I_{RR}=0.25\text{A}$			35	ns
		$I_F=1\text{A}, V_R=30\text{V}, di/dt=200\text{A}/\mu\text{s}$		21	35	ns

Thermal characteristics

Parameter	Symbol	Typ	MAX	Units
Junction-to-Case	R_{thJC}	-	4.5	$^\circ\text{C}/\text{W}$

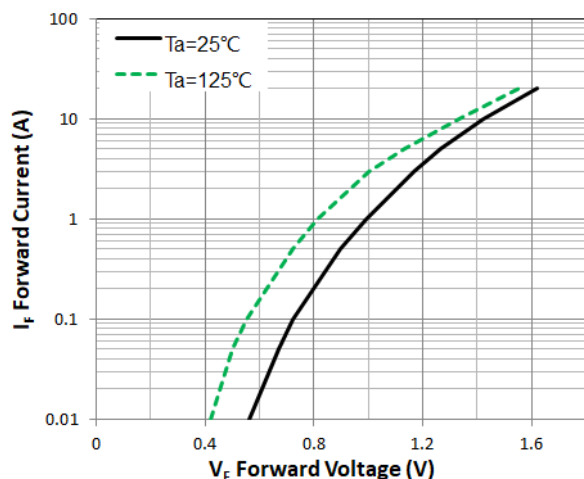


Figure 1. Forward Characteristic(typ.)

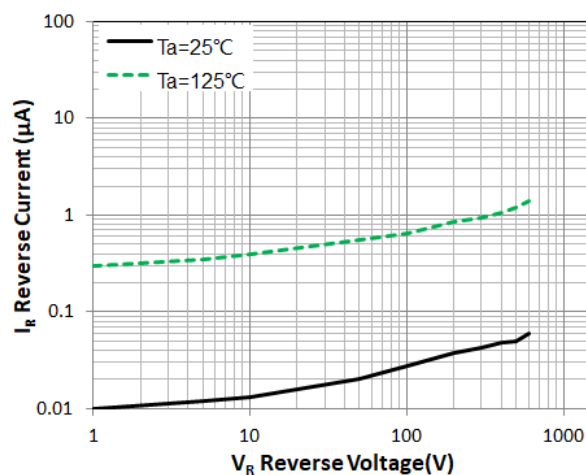
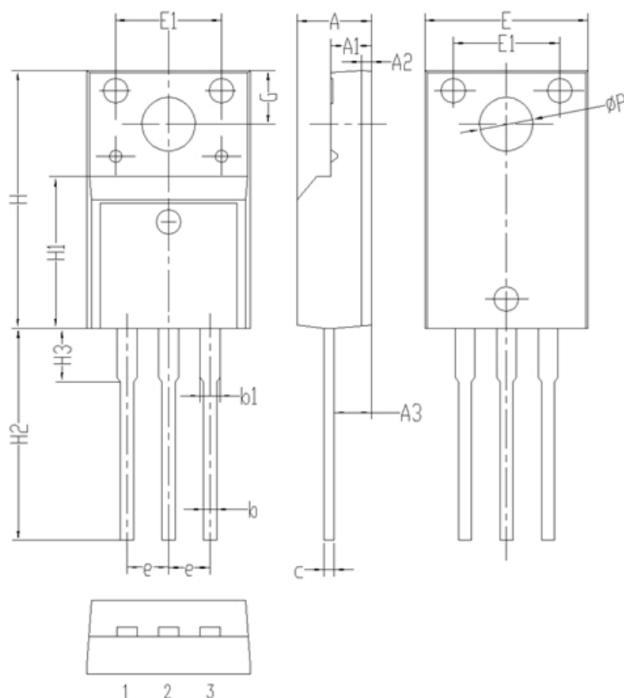


Figure 2. Reverse Characteristic(typ.)

Package Information

TO-220F PACKAGE



Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.35	4.75
A1	2.30	2.70
A2	0.40	0.80
A3	2.10	2.50
b	0.60	1.00
b1	1.00	1.40
c	0.30	0.70
e	2.30	2.70
E	9.80	10.20
E1	6.30	6.70
H	15.60	16.00
H1	8.80	9.20
H2	12.90	13.50
H3	3.10	3.50
G	3.10	3.50
ΦP	3.10	3.50